

(51) International Patent Classification ⁶ : H01L 23/525		A3	(11) International Publication Number: WO 97/15068 (43) International Publication Date: 24 April 1997 (24.04.97)
(21) International Application Number: PCT/US96/15872 (22) International Filing Date: 3 October 1996 (03.10.96) (30) Priority Data: 08/538,962 4 October 1995 (04.10.95) US (71) Applicant: ACTEL CORPORATION [US/US]; 955 East Arques Avenue, Sunnyvale, CA 94086 (US). (72) Inventors: HAWLEY, Frank, W.; 1360 Capri Drive, Campbell, CA 95008 (US). ELTOUKHY, Abdelshafy, A.; 509 Churchill Park Drive, San Jose, CA 95136 (US). McCOLLUM, John, L.; 19810 Merribrook Drive, Saratoga, CA 95070 (US). (74) Agents: D'ALESSANDRO, Kenneth et al.; D'Alessandro & Ritchie, P.O. Box 640640, San Jose, CA 95164-0640 (US).		(81) Designated States: CA, JP, KR, European patent (AT, BE, CH, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE). Published <i>With international search report. Before the expiration of the time limit for amending the claims and to be republished in the event of the receipt of amendments.</i> (88) Date of publication of the international search report: 19 June 1997 (19.06.97)	

A cross-sectional view of a semiconductor device. A central opening 44 is formed in a layer 34. The opening is filled with a material 42. The layer 34 is composed of two parts: a top layer 50 and a bottom layer 48. The bottom layer 48 is labeled as ILD (Interlayer Dielectric). The top layer 50 is also labeled as ILD. The bottom layer 48 is further labeled as 52. The top layer 50 is further labeled as 40. The bottom layer 48 is further labeled as 38. The top layer 50 is further labeled as 36.

A metal-to-metal antifuse disposed between two aluminum metallization layers (38, 50) in a CMOS integrated circuit or similar structure includes an antifuse material layer (42) having an aluminium-free conductive link. The aluminium-free link is formed by forming a first barrier metal layer out of tin having a first thickness (40, 48), a second barrier metal layer out of tin having a second thickness (48, 40) which may be less than said first thickness, the first and second barrier metal layers separating the antifuse material layer from first and second electrodes. The antifuse is programmed by applying a voltage potential capable of programming the antifuse across the electrodes with the more positive side of the potential applied to the electrode adjacent the barrier metal layer having the least thickness. In another aspect of the invention, an antifuse having a first barrier metal layer of a first thickness and a second barrier metal layer of a second thickness may be fabricated wherein the first thickness is less than the second thickness and wherein programming of the antifuse is accomplished by placing the more positive voltage of the programming voltage supply on the electrode of the antifuse adjacent the first barrier metal layer.

FOR THE PURPOSES OF INFORMATION ONLY

Codes used to identify States party to the PCT on the front pages of pamphlets publishing international applications under the PCT.

AM	Armenia	GB	United Kingdom	MW	Malawi
AT	Austria	GE	Georgia	MX	Mexico
AU	Australia	GN	Guinea	NE	Niger
BB	Barbados	GR	Greece	NL	Netherlands
BE	Belgium	HU	Hungary	NO	Norway
BF	Burkina Faso	IE	Ireland	NZ	New Zealand
BG	Bulgaria	IT	Italy	PL	Poland
BJ	Benin	JP	Japan	PT	Portugal
BR	Brazil	KE	Kenya	RO	Romania
BY	Belarus	KG	Kyrgyzstan	RU	Russian Federation
CA	Canada	KP	Democratic People's Republic of Korea	SD	Sudan
CF	Central African Republic	KR	Republic of Korea	SE	Sweden
CG	Congo	KZ	Kazakhstan	SG	Singapore
CH	Switzerland	LI	Liechtenstein	SI	Slovenia
CI	Côte d'Ivoire	LK	Sri Lanka	SK	Slovakia
CM	Cameroon	LR	Liberia	SN	Senegal
CN	China	LT	Lithuania	SZ	Swaziland
CS	Czechoslovakia	LU	Luxembourg	TD	Chad
CZ	Czech Republic	LV	Latvia	TG	Togo
DE	Germany	MC	Monaco	TJ	Tajikistan
DK	Denmark	MD	Republic of Moldova	TT	Trinidad and Tobago
EE	Estonia	MG	Madagascar	UA	Ukraine
ES	Spain	ML	Mali	UG	Uganda
FI	Finland	MN	Mongolia	US	United States of America
FR	France	MR	Mauritania	UZ	Uzbekistan
GA	Gabon			VN	Viet Nam

INTERNATIONAL SEARCH REPORT

Inte: onal Application No
PCT/US 96/15872

A. CLASSIFICATION OF SUBJECT MATTER
IPC 6 H01L23/525

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)
IPC 6 H01L

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	WO 93 04499 A (CROSSPOINT SOLUTIONS INC) 4 March 1993 see page 7, line 13 - page 10, line 30; figures 1-4 ---	1,3,5-7, 9,11-18
A	EP 0 661 745 A (ACTEL CORP) 5 July 1995 see column 3, line 48 - column 5, line 24 ---	1,3,5-7, 9,11-18
A	EP 0 660 408 A (UNITED TECHNOLOGIES CORP) 28 June 1995 see column 4, line 47 - column 8, line 52; figures 3-9 ---	1,3,5-7, 9,11-18
A	US 5 403 778 A (KWOK SIANG P ET AL) 4 April 1995 see column 4, line 56 - column 5, line 63; figures 2-5 ---	1,3,5-7, 9,11-18
-/--		

☒ Further documents are listed in the continuation of box C.

☒ Patent family members are listed in annex.

* Special categories of cited documents :

- *A* document defining the general state of the art which is not considered to be of particular relevance
- *E* earlier document but published on or after the international filing date
- *L* document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)
- *O* document referring to an oral disclosure, use, exhibition or other means
- *P* document published prior to the international filing date but later than the priority date claimed

- *T* later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention
- *X* document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone
- *Y* document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.
- *&* document member of the same patent family

Date of the actual completion of the international search

28 January 1997

Date of mailing of the international search report

07.05.97

Name and mailing address of the ISA

European Patent Office, P.B. 5818 Patentlaan 2
NL - 2280 HV Rijswijk
Tel. (+ 31-70) 340-2040, Tx. 31 651 epo nl,
Fax (+ 31-70) 340-3016

Authorized officer

Le Minh, I

INTERNATIONAL SEARCH REPORT

International Application No.

PCT/US 96/15872

C.(Continuation) DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
P,A	US 5 485 031 A (ZHANG GUOBIAO ET AL) 16 January 1996 see column 3, line 31 - column 5, line 37 see column 6, line 36 - line 61 see column 8, line 31 - line 56; figure 8 -----	1,3,5-7, 9,11-18

INTERNATIONAL SEARCH REPORT

Information on patent family members

International Application No

PCT/US 96/15872

Patent document cited in search report	Publication date	Patent family member(s)	Publication date
WO-A-9304499	04-03-93	NONE	
EP-A-0661745	05-07-95	US-A- 5381035	10-01-95
		JP-A- 7273207	20-10-95
		US-A- 5525830	11-06-96
		US-A- 5543656	06-08-96
EP-A-0660408	28-06-95	NONE	
US-A-5403778	04-04-95	EP-A- 0662712	12-07-95
		JP-A- 8051158	20-02-96
US-A-5485031	16-01-96	NONE	